

NUP4304MR6T1G

Data Sheet

Low Capacitance Diode Array for ESD Protection in Four Data Lines, Rectifiers Low Cap. for ESD Protection in 4 Line

Manufacturers ON Semiconductor, LLC

Package/Case SC-74-6

Product Type Circuit Protection

RoHS Rohs

Lifecycle



Images are for reference only

ONSEMI

Please submit RFQ for NUP4304MR6T1G or Email to us: sales@ovaga.com We will contact you in 12 hours.



General Description

NUP4304MR6 is a micro-integrated device designed to provide protection for sensitive components from possible harmful electrical transients; for example, ESD (electrostatic discharge).

Features Application

Low Capacitance (1.5 pF Maximum between I/O Lines)

Single Package Integration Design

Provides ESD Protection for JEDEC Standards JESD22:Machine = Class 3B

Protection for IEC61000-4-2 (Level 4):8.0 kV (Contact) and 15 kV (Air)

Ensures Data Line Speed and Integrity

Fewer Components and Less Board Space

Direct the Transient to either Positive Side or to Ground

Related Products



NUP4114UCLW1T2G

ON Semiconductor, LLC SC-88



NUP4302MR6T1G

ON Semiconductor, LLC TSOP-6



NUP4301MR6T1G

ON Semiconductor, LLC SC-74-6



SRDA3.3-4DR2G

ON Semiconductor, LLC SO-8



SZNUP4304MR6T1G

ON Semiconductor, LLC TSOP-6



ESD8011MUT5G

ON Semiconductor, LLC X3DFN-2



NCP347MTAETBG

ON Semiconductor, LLC WDFN-10



NCP347MTAHTBG

ON Semiconductor, LLC WDFN10